

1.5V Drive Pch MOSFET

RZL035P01

●Structure

Silicon P-channel MOSFET

●Features

- 1) Low on-resistance.
- 2) High power package.
- 3) Low voltage drive. (1.5V)

●Application

Switching

●Packaging specifications

Type	Package	Taping
	Code	TR
	Basic ordering unit (pieces)	3000
RZL035P01		○

●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V _{DSS}	−12	V
Gate-source voltage		V _{GSS}	±10	V
Drain current	Continuous	I _D	±3.5	A
	Pulsed	I _{DP} *1	±14	A
Source current (Body diode)	Continuous	I _S	−0.8	A
	Pulsed	I _{SP} *1	−14	A
Total power dissipation		P _D *2	1.0	W
Channel temperature		T _{ch}	150	°C
Range of Storage temperature		T _{stg}	−55 to +150	°C

 *1 $P_w \leq 10\mu s$, Duty cycle $\leq 1\%$

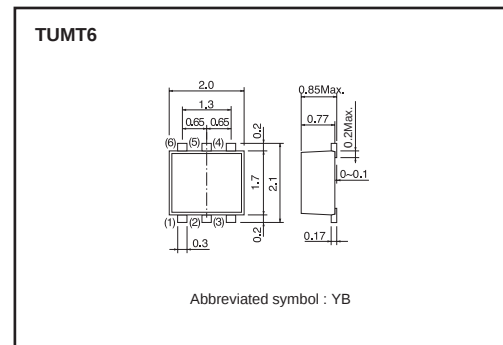
*2 Mounted on a ceramic board

●Thermal resistance

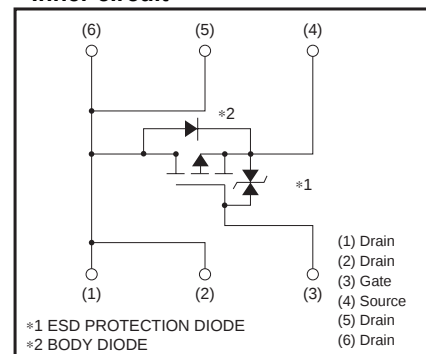
Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th}(ch-a)$ *	125	°C / W

* When mounted on a ceramic board.

●Dimensions (Unit : mm)



●Inner circuit



●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	–	–	± 10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	–12	–	–	V	$I_D = -1mA, V_{GS} = 0V$
Zero gate voltage drain current	I_{DSS}	–	–	–1	μA	$V_{DS} = -12V, V_{GS} = 0V$
Gate threshold voltage	$V_{GS(th)}$	–0.3	–	–1.0	V	$V_{DS} = -6V, I_D = -1mA$
Static drain-source on-state resistance	$R_{DS(on)}$ *	–	26	36	m Ω	$I_D = -3.5A, V_{GS} = -4.5V$
		–	36	50	m Ω	$I_D = -1.7A, V_{GS} = -2.5V$
		–	46	69	m Ω	$I_D = -1.7A, V_{GS} = -1.8V$
		–	66	132	m Ω	$I_D = -0.7A, V_{GS} = -1.5V$
Forward transfer admittance	$ Y_{fs} $ *	5.5	–	–	S	$V_{DS} = -6V, I_D = -3.5A$
Input capacitance	C_{iss}	–	1940	–	pF	$V_{DS} = -6V$
Output capacitance	C_{oss}	–	260	–	pF	$V_{GS} = 0V$
Reverse transfer capacitance	C_{rss}	–	240	–	pF	$f = 1MHz$
Turn-on delay time	$t_{d(on)}$ *	–	10	–	ns	$V_{DD} \doteq -6V$
Rise time	t_r *	–	50	–	ns	$I_D = -1.7A$
Turn-off delay time	$t_{d(off)}$ *	–	350	–	ns	$V_{GS} = -4.5V$
Fall time	t_f *	–	180	–	ns	$R_L \doteq 3.5\Omega$
Total gate charge	Q_g *	–	20	–	nC	$V_{DD} \doteq -6V, I_D = -3.5A$
Gate-source charge	Q_{gs} *	–	3.5	–	nC	$V_{GS} = -4.5V$
Gate-drain charge	Q_{gd} *	–	3.0	–	nC	$R_L \doteq 1.7\Omega, R_G = 10\Omega$

* Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD} *	–	–	–1.2	V	$I_S = -3.5A, V_{GS} = 0V$

* Pulsed

●Electrical characteristics curves

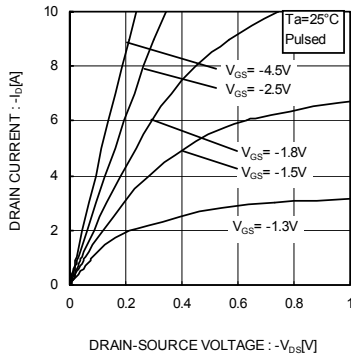


Fig.1 Typical output characteristics (I)

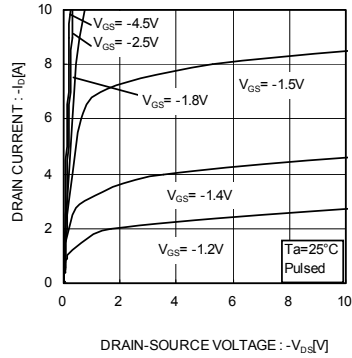


Fig.2 Typical output characteristics (II)

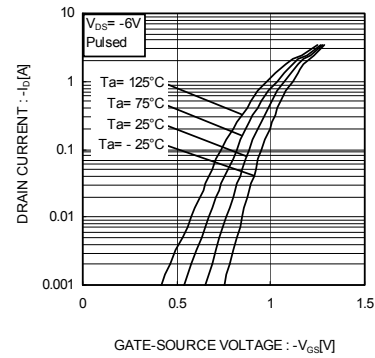


Fig.3 Typical Transfer Characteristics

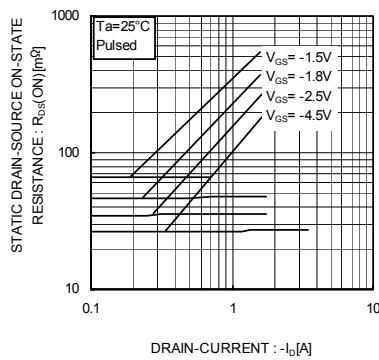


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current(I)

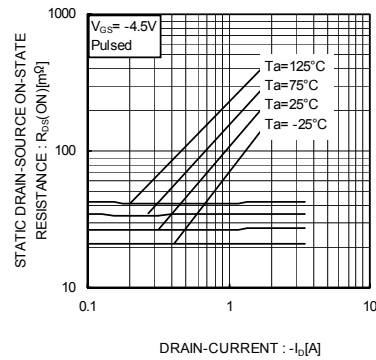


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

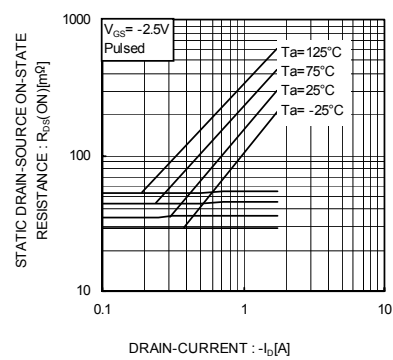


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)

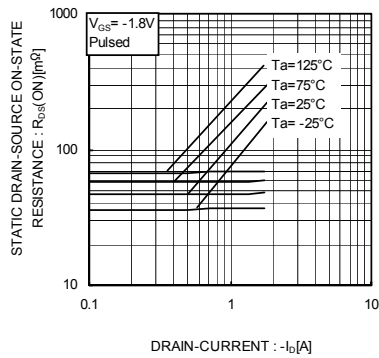


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

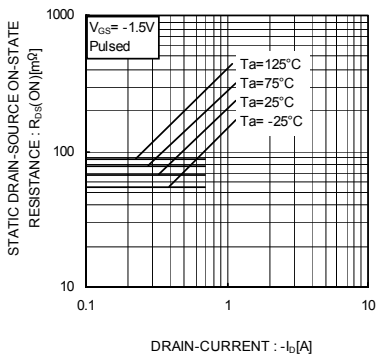


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current(IV)

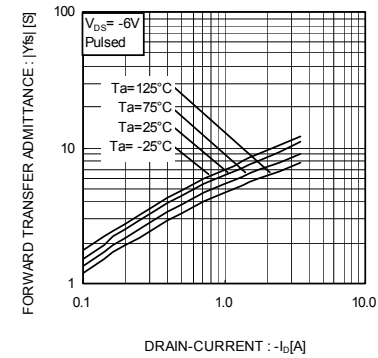


Fig.9 Forward Transfer Admittance vs. Drain Current

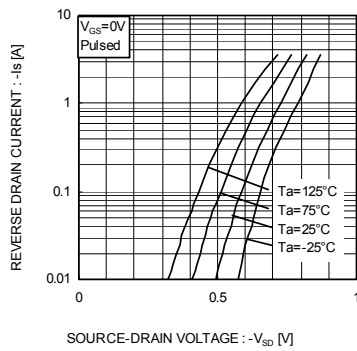


Fig.10 Reverse Drain Current vs. Source-Drain Voltage

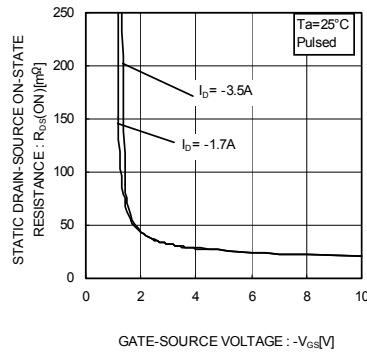


Fig.11 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

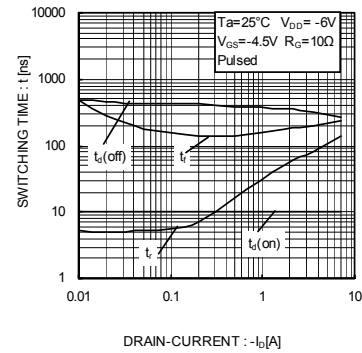


Fig.12 Switching Characteristics

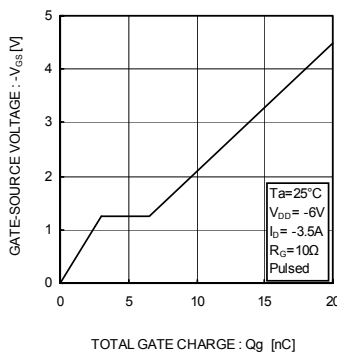


Fig.13 Dynamic Input Characteristics

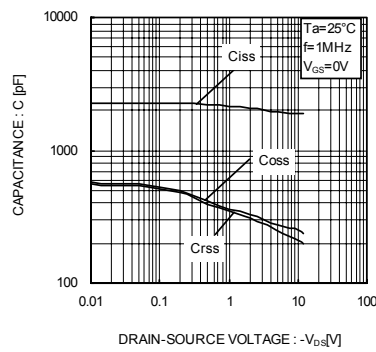


Fig.14 Typical Capacitance vs. Drain-Source Voltage

●Measurement circuits

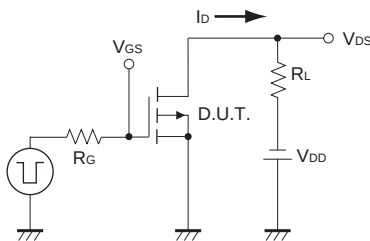


Fig.1-1 Switching Time Measurement Circuit

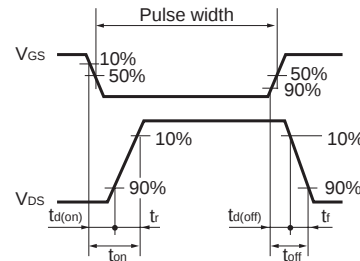


Fig.1-2 Switching Waveforms

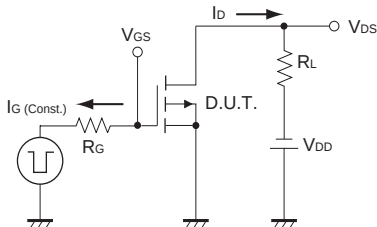


Fig.2-1 Gate Charge Measurement Circuit

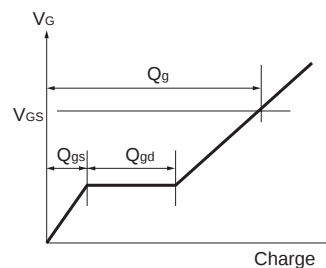


Fig.2-2 Gate Charge Waveform

●Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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